	Hits	Search Text	DBs	Time Stamp
1	23	nano adj dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:23
2	1	nano adj dots with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:30
3	4	nano adj dots with holes	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:23
4	14	nano?dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:23
5	292	dots with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:31
6	56	quantum adj dots with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:31
7	6997	(dots holes) with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:22
8	173	(dots holes) with transistor and (cylinder cylinders)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:23
9	1	(dots holes) with transistor and (cylinder cylinders) and nano?dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:24

	Hits	Search Text	DBs	Time Stamp
10	0	(dots holes) with transistor and (cylinder cylinders) and quantum adj dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:24
11	3	(dots holes) with transistor and nano?dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:24
12	70	(dots holes) with transistor and quantum adj dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:26
13	71	("6709929" "4796082" "4568960" "5217943" "5593562" "5714766" "5923046" "5937295" "6165842" "6194237" "6183890" "7333214" "6424004" "6597036" "6670670" "5899734" "6440637" "6632694" "6791105" "6151347" "6476409" "5364742" "6153452" "6753200" "6773950" "6734105" "5202290" "5694161" "5997956" "6218175" "6268273" "6435656" "5681396" "5062877" "5264722" "530661" "6037243").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:46
14	22	("6489587" "6767771" "5509554" "6440332" "6627117" "6668628" "6381166" "5017982" "5572461" "4266238" "5414665").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:43
15	9813	transistor and charge adj storage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:46
16	5	("6489587" "6767771" "5509554" "6440332" "6627117" "6668628" "6381166" "5017982" "5572461" "4266238" "5414665").pn. and dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:44

	Hits	Search Text	DBs	Time Stamp
17	627	transistor and charge adj storage adj (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:46
18	0	transistor and charge adj storage adj (layer film) and sacrifical adj (layer film) and metal adj (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:51
19	38	("6709929" "4796082" "4568960" "5217943" "5593562" "5714766" "5923046" "5937295" "6165842" "6194237" "6183890" "7333214" "6424004" "6597036" "6670670" "5899734" "6440637" "6632694" "6791105" "6151347" "6476409" "5364742" "6153452" "6753200" "6773950" "6734105" "5202290" "5694161" "5997956" "6218175" "6268273" "6435656" "5681396" "5062877" "5264722" "530661" "6037243").pn. and dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:47
20	64	transistor and charge adj storage adj (layer film) and oxide adj (layer film) and metal adj (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 16:32
21	43	transistor and charge adj storage adj (layer film) and oxide adj (layer film) and metal adj (layer film) and (dots holes)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 14:52
22	18	transistor and charge adj storage adj (layer film) and dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 15:56
23	4	transistor and charge adj storage adj (layer film) and dots and metal adj (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 15:56

	Hits	Search Text	DBs	Time Stamp
24	206	transistor and metal adj (layer film) same (anodizing anodized)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 16:33
25	46	transistor and metal adj (layer film) same (anodizing anodized) same (oxidation oxidizing oxidized)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/04 16:33
26	22	transistor and metal adj (layer film) same (anodizing anodized) same (oxidation oxidizing oxidized) and (holes dots)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:06
27	88	(transistor transistors) same metal adj (layer film) and metal adj (layer film) same (anodizing anodized)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:07
28	2	(transistor transistors) same metal adj (layer film) and metal adj (layer film) same (anodizing anodized) same (oxidation oxidizing oxidized) and (holes dots)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:08
29	18	(transistor transistors) same metal adj (layer film) and metal adj (layer film) same (anodizing anodized) same (oxidation oxidizing oxidized)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:09
30	1070	438/151.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29
31	368	438/201.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29

	Hits	Search Text	DBs	Time Stamp
32	196	438/285.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29
33	314	438/430.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29
34	164	438/431.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29
35	101	438/432.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:29
36	477	438/435.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
37	99	438/590.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
38	235	438/800.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
39	321	257/24.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
40	232	257/65.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30

	Hits	Search Text	DBs	Time Stamp
41	1419	257/66.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
42	1087	257/192.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
43	470	"977"/$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:30
44	0	"977"/$.ccls. and nano adj dots	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:31
45	47	"977"/$.ccls. and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/02/05 16:31